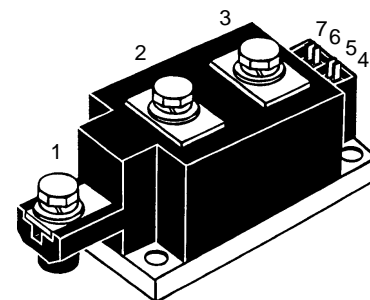


Thyristor Modules

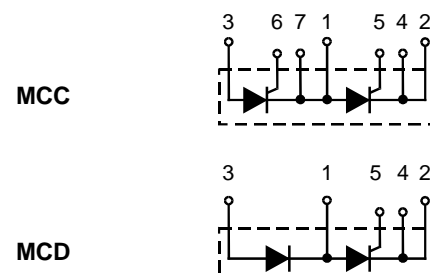
Thyristor/Diode Modules

$I_{TRMS} = 2x 450 A$
 $I_{TAVM} = 2x 250 A$
 $V_{RRM} = 1200-1800 V$

| V_{RSM} V_{DSM} V | V_{RRM} V_{DRM} V | Type | |
|-----------------------------|-----------------------------|---------------|---------------|
| 1300 | 1200 | MCC 255-12io1 | MCD 255-12io1 |
| 1500 | 1400 | MCC 255-14io1 | MCD 255-14io1 |
| 1700 | 1600 | MCC 255-16io1 | MCD 255-16io1 |
| 1900 | 1800 | MCC 255-18io1 | MCD 255-18io1 |



| Symbol | Test Conditions | Maximum Ratings | |
|--|--|---|--|
| I_{TRMS}, I_{FRMS} I_{TAVM}, I_{FAVM} | $T_{VJ} = T_{VJM}$ $T_C = 85^\circ C; 180^\circ$ sine | 450 | A |
| I_{TSM}, I_{FSM} | $T_{VJ} = 45^\circ C;$ $V_R = 0$ | t = 10 ms (50 Hz) t = 8.3 ms (60 Hz) | 9000 A 9600 A |
| | $T_{VJ} = T_{VJM}$ $V_R = 0$ | t = 10 ms (50 Hz) t = 8.3 ms (60 Hz) | 7800 A 8600 A |
| $\int i^2 dt$ | $T_{VJ} = 45^\circ C$ $V_R = 0$ | t = 10 ms (50 Hz) t = 8.3 ms (60 Hz) | 405 000 A ² s 382 000 A ² s |
| | $T_{VJ} = T_{VJM}$ $V_R = 0$ | t = 10 ms (50 Hz) t = 8.3 ms (60 Hz) | 304 000 A ² s 307 000 A ² s |
| $(di/dt)_{cr}$ | $T_{VJ} = T_{VJM}$ f = 50 Hz, $t_p = 200 \mu s$ $V_D = 2/3 V_{DRM}$ $I_G = 1 A,$ $di_G/dt = 1 A/\mu s$ | repetitive, $I_T = 860 A$ | 100 A/ μs |
| | | non repetitive, $I_T = I_{TAVM}$ | 500 A/ μs |
| $(dv/dt)_{cr}$ | $T_{VJ} = T_{VJM}; V_{DR} = 2/3 V_{DRM}$ $R_{GK} = \infty;$ method 1 (linear voltage rise) | | 1000 V/ μs |
| P_{GM} | $T_{VJ} = T_{VJM}$ $I_T = I_{TAVM}$ | $t_p = 30 \mu s$ $t_p = 500 \mu s$ | 120 W 60 W |
| P_{GAV} V_{RGM} | | | 20 W 10 V |
| T_{VJ} T_{VJM} T_{stg} | | | -40...+130 °C 130 °C -40...+125 °C |
| V_{ISOL} | 50/60 Hz, RMS $I_{ISOL} \leq 1 mA$ | t = 1 min t = 1 s | 3000 V~ 3600 V~ |
| M_d | Mounting torque (M6) Terminal connection torque (M8) | | 4.5-7/40-62 Nm/lb.in. 11-13/97-115 Nm/lb.in. |
| Weight | Typical including screws | | 750 g |



Features

- International standard package
- Direct copper bonded Al₂O₃-ceramic with copper base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered E 72873
- Keyed gate/cathode twin pins

Applications

- Motor control, softstarter
- Power converter
- Heat and temperature control for industrial furnaces and chemical processes
- Lighting control
- Solid state switches

Advantages

- Simple mounting
- Improved temperature and power cycling
- Reduced protection circuits

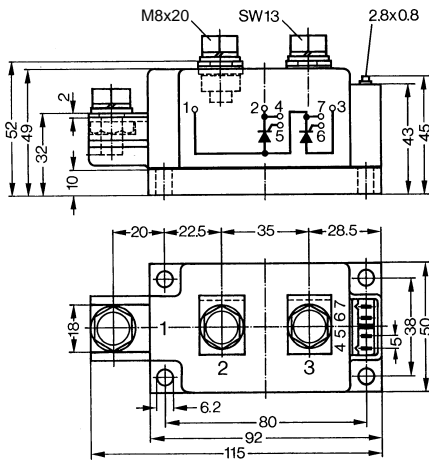
Data according to IEC 60747 and refer to a single thyristor/diode unless otherwise stated. IXYS reserves the right to change limits, test conditions and dimensions

| Symbol | Test Conditions | Characteristic Values |
|--------------------|--|----------------------------------|
| I_{RRM}, I_{DRM} | $T_{VJ} = T_{VJM}; V_R = V_{RRM}; V_D = V_{DRM}$ | 40 mA |
| V_T, V_F | $I_T, I_F = 600 \text{ A}; T_{VJ} = 25^\circ\text{C}$ | 1.36 V |
| V_{T0} | For power-loss calculations only ($T_{VJ} = 130^\circ\text{C}$) | 0.8 V |
| r_T | | 0.68 mΩ |
| V_{GT} | $V_D = 6 \text{ V}; T_{VJ} = 25^\circ\text{C}$ | 2 V |
| | $T_{VJ} = -40^\circ\text{C}$ | 3 V |
| I_{GT} | $V_D = 6 \text{ V}; T_{VJ} = 25^\circ\text{C}$ | 150 mA |
| | $T_{VJ} = -40^\circ\text{C}$ | 220 mA |
| V_{GD} | $T_{VJ} = T_{VJM}; V_D = 2/3 V_{DRM}$ | 0.25 V |
| I_{GD} | $T_{VJ} = T_{VJM}; V_D = 2/3 V_{DRM}$ | 10 mA |
| I_L | $T_{VJ} = 25^\circ\text{C}; t_p = 30 \mu\text{s}; V_D = 6 \text{ V}$ $I_G = 0.45 \text{ A}; di_G/dt = 0.45 \text{ A}/\mu\text{s}$ | 200 mA |
| I_H | $T_{VJ} = 25^\circ\text{C}; V_D = 6 \text{ V}; R_{GK} = \infty$ | 150 mA |
| t_{gd} | $T_{VJ} = 25^\circ\text{C}; V_D = 1/2 V_{DRM}$ $I_G = 1 \text{ A}; di_G/dt = 1 \text{ A}/\mu\text{s}$ | 2 μs |
| t_q | $T_{VJ} = T_{VJM}; I_T = 300 \text{ A}, t_p = 200 \mu\text{s}; -di/dt = 10 \text{ A}/\mu\text{s}$ typ. $V_R = 100 \text{ V}; dv/dt = 50 \text{ V}/\mu\text{s}; V_D = 2/3 V_{DRM}$ | 200 μs |
| Q_S | $T_{VJ} = 125^\circ\text{C}; I_T, I_F = 300 \text{ A}; -di/dt = 50 \text{ A}/\mu\text{s}$ | 760 μC |
| I_{RM} | | 275 A |
| R_{thJC} | per thyristor (diode); DC current per module | 0.140 K/W |
| R_{thJK} | per thyristor (diode); DC current per module | 0.07 K/W 0.18 K/W 0.09 K/W |
| | other values see Fig. 8/9 | |
| d_s | Creeping distance on surface | 12.7 mm |
| d_a | Creepage distance in air | 9.6 mm |
| a | Maximum allowable acceleration | 50 m/s ² |

Optional accessories for modules
 Keyed Gate/Cathode twin plugs with wire length = 350 mm, gate = yellow, cathode = red
 Type ZY 180 L (L = Left for pin pair 4/5) } UL 758, style 1385,
 Type ZY 180 R (R = Right for pin pair 6/7) } CSA class 5851, guide 460-1-1

Dimensions in mm (1 mm = 0.0394")

MCC 255



MCD 255

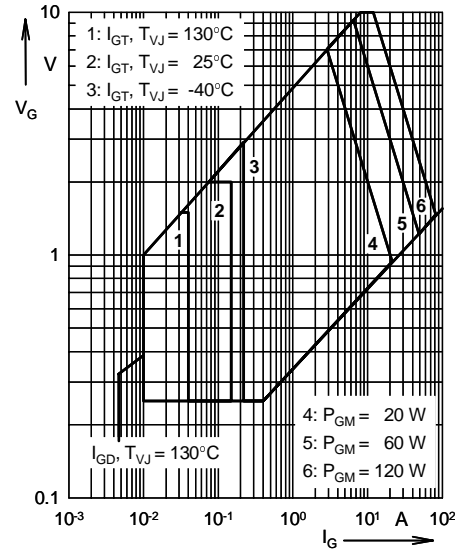
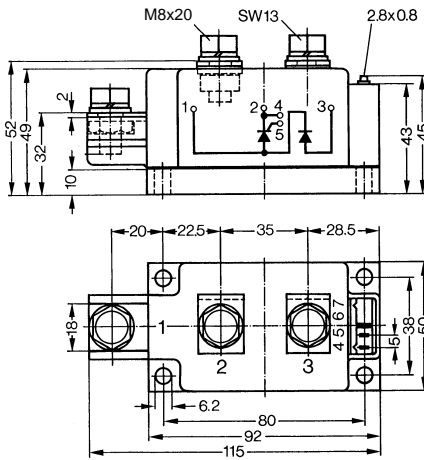


Fig. 1 Gate trigger characteristics

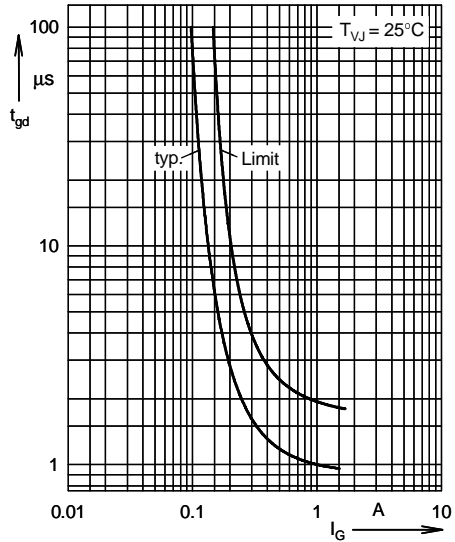


Fig. 2 Gate trigger delay time

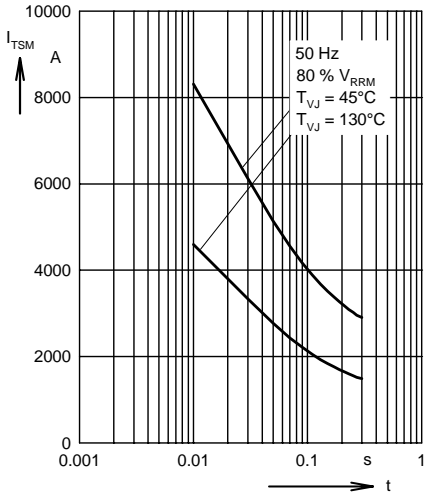


Fig. 3 Surge overload current
 I_{TSM}, I_{FSM} : Crest value, t: duration

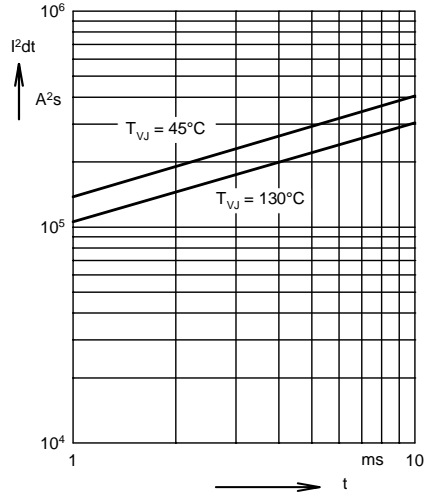


Fig. 4 $\int i^2 dt$ versus time (1-10 ms)

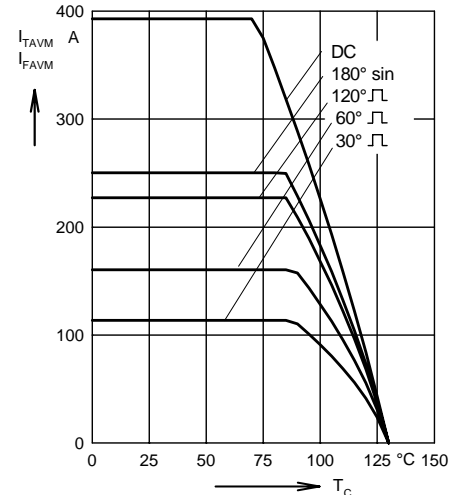


Fig. 4a Maximum forward current at case temperature

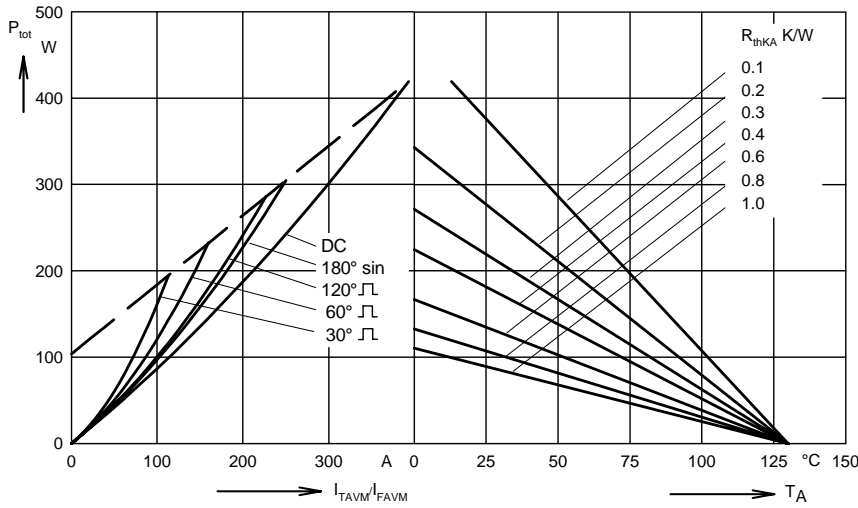


Fig. 5 Power dissipation versus on-state current and ambient temperature (per thyristor or diode)

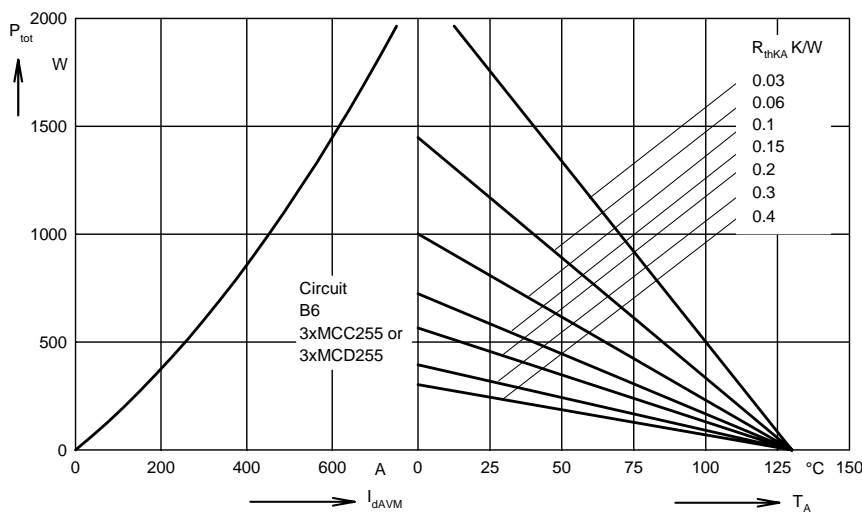


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

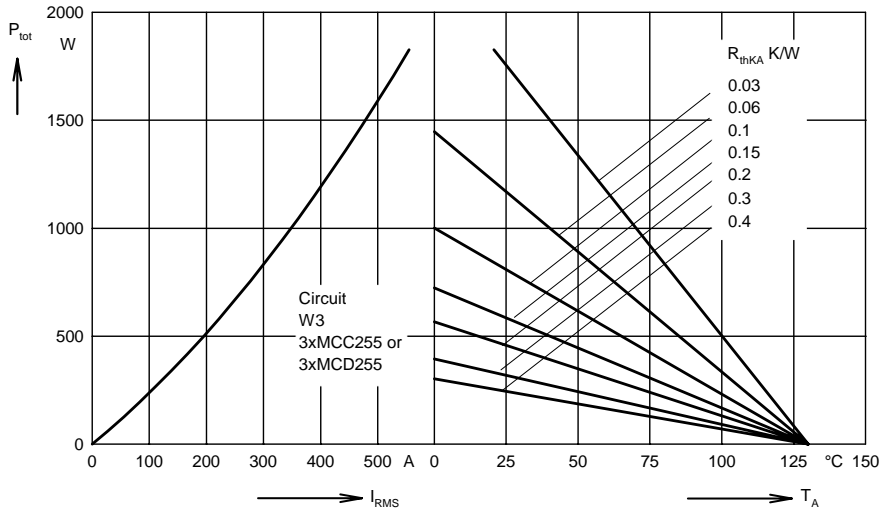


Fig. 7 Three phase AC-controller: Power dissipation versus RMS output current and ambient temperature

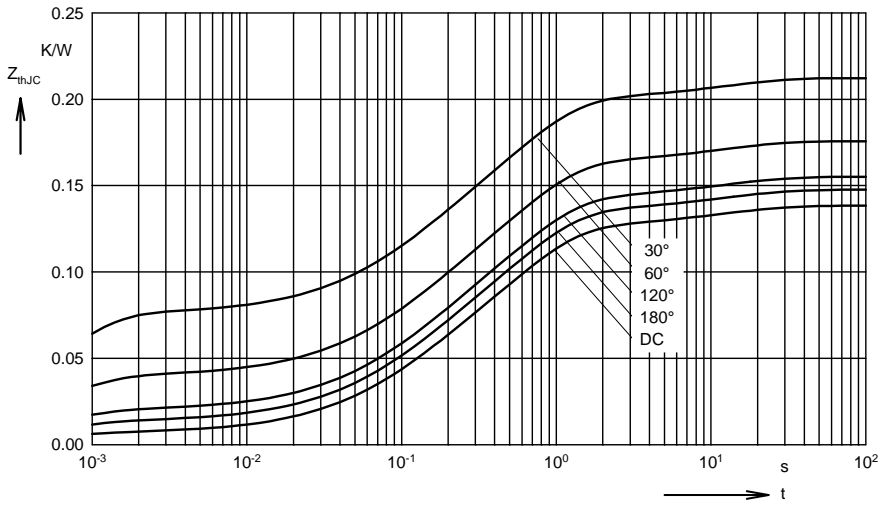


Fig. 8 Transient thermal impedance junction to case (per thyristor or diode)

R_{thJC} for various conduction angles d:

| d | R_{thJC} (K/W) |
|------|------------------|
| DC | 0.139 |
| 180° | 0.148 |
| 120° | 0.156 |
| 60° | 0.176 |
| 30° | 0.214 |

Constants for Z_{thJC} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|---|-----------------|-----------|
| 1 | 0.0066 | 0.00054 |
| 2 | 0.0358 | 0.098 |
| 3 | 0.0831 | 0.54 |
| 4 | 0.0129 | 12 |

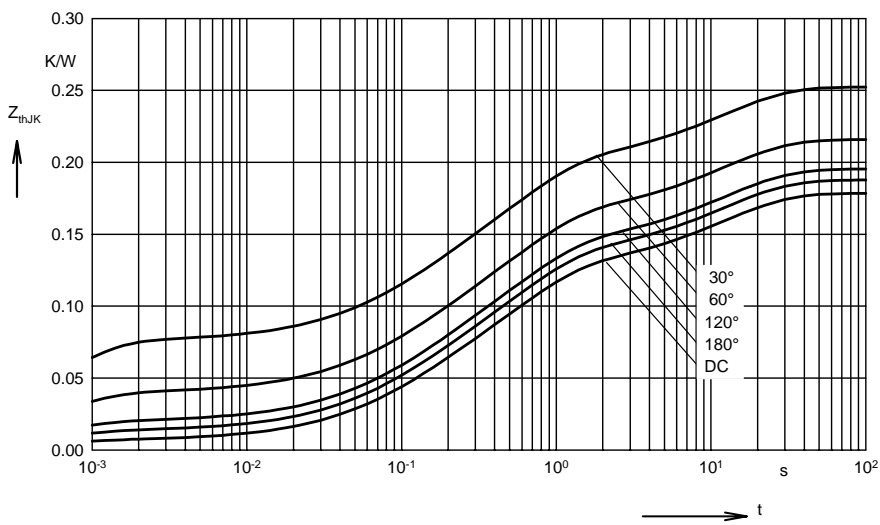


Fig. 9 Transient thermal impedance junction to heatsink (per thyristor or diode)

R_{thJK} for various conduction angles d:

| d | R_{thJK} (K/W) |
|------|------------------|
| DC | 0.179 |
| 180° | 0.188 |
| 120° | 0.196 |
| 60° | 0.216 |
| 30° | 0.254 |

Constants for Z_{thJK} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|---|-----------------|-----------|
| 1 | 0.0066 | 0.00054 |
| 2 | 0.0358 | 0.098 |
| 3 | 0.0831 | 0.54 |
| 4 | 0.0129 | 12 |
| 5 | 0.04 | 12 |